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# Photoluminescence and electroluminescence of deep red iridium(III) complexes with 2,3-diphenylquinoxaline derivatives and 1,3,4-oxadiazole derivatives ligands†

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Four iridium(III) complexes (**Ir1** to **Ir4**) containing 2,3-diphenylquinoxaline derivatives with or without fluoro-substituted on different positions (**L1**: 2,3-diphenylquinoxaline; **L2**: 6,7-difluoro-2,3-diphenylquinoxaline; **L3**: 2,3-bis(4-fluorophenyl)quinoxaline; **L4**: 6,7-difluoro-2,3-bis(4-fluorophenyl)quinoxaline) as main ligands and 2-(5-phenyl-1,3,4-oxadiazol-2-yl)phenol (**HPOP**) as ancillary ligand were synthesized and investigated. All the complexes emit deep red photoluminescence (PL) (**Ir1**:  $\lambda_{\text{max}}$ : 645 nm; **Ir2**:  $\lambda_{\text{max}}$ : 650 nm; **Ir3**:  $\lambda_{\text{max}}$ : 634 nm; **Ir4**:  $\lambda_{\text{max}}$ : 639 nm). Moreover, the electron mobility of the complexes **Ir3** and **Ir4** is higher than that of the electron transport material Alq<sub>3</sub> (tris-(8-hydroxyquinoline)aluminium), which is beneficial for their performances in organic light-emitting diodes (OLEDs). The OLEDs with single- or double-emitting layers (EML) were fabricated using **Ir3** or **Ir4** as the emitter. The double-EML device using **Ir4** with the structure of ITO (indium-tin-oxide)/MoO<sub>3</sub> (molybdenum oxide, 5 nm)/TAPC (di-[4-(*N,N*-ditolyl-amino)-phenyl]cyclohexane, 30 nm)/TcTa (4,4',4''-tris(carbazol-9-yl) triphenylamine): **Ir4** (2 wt%, 10 nm)/26DCzPPy (2,6-bis(3-(carbazol-9-yl)phenyl)pyridine): **Ir4** (2 wt%, 10 nm)/TmPyPB (1,3,5-tri(*m*-pyrid-3-yl-phenyl)benzene, 40 nm)/LiF (1 nm)/Al (100 nm) displays good electroluminescence (EL) performances with maximum luminance, current efficiency, power efficiency and external quantum efficiency of up to 20 676 cd m<sup>-2</sup>, 14.0 cd A<sup>-1</sup>, 12.0 lm W<sup>-1</sup> and 17.8%, respectively, and the efficiency roll-off ratio is mild. The results suggest that the number and position of fluoro-substituents can affect photophysical, electrochemical and electroluminescent properties of the Ir(III) complexes, which are potential deep red phosphorescent materials for specific OLED applications.

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## Introduction

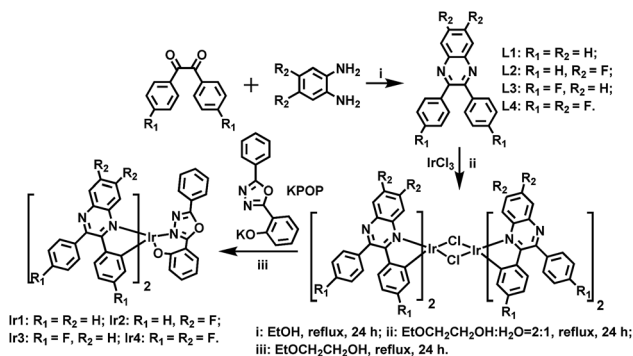
Iridium(III) complexes are widely investigated and utilized in organic light-emitting diodes (OLEDs) due to their encouraging advantages such as thermal stability, flexible color tunability and high quantum efficiencies.<sup>1</sup> The energy from both singlet and triplet states can be harvested because of the strong spin-orbit coupling caused by the heavy metal atom, leading to high

phosphorescence quantum yields and theoretical internal quantum efficiency of OLEDs up to 100%.<sup>2</sup> For high quality red-green-blue (RGB) displays and high color purity white OLEDs (WOLEDs), red and deep red iridium(III) dopants are one of the most essential chromaticity components.<sup>3</sup> Additionally, deep red emitters are largely used in specific fields, such as optical signal processing, luminescent sensing, bioimaging and photodynamic therapy.<sup>4</sup> However, compared with the well-developed green, yellow and orange phosphors, the development of efficient deep red phosphors and OLEDs remains a challenging issue. The quantum yields of red emitters tend to be reduced for the reason that the low-lying excited state energy can be easily quenched.<sup>5</sup> On the other hand, it is known that the hole mobility of most hole transport materials is roughly 2–3 orders of magnitude higher than the electron mobility of electron transport materials, thus, highly efficiency OLEDs suffer from serious efficiency roll-off which is attributed to the deterioration of charge carrier balance. In all, it is imperative to design and synthesize deep red Ir(III) complexes with good electron mobility to fulfill deep red OLEDs with low efficiency roll-off.

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† Electronic supplementary information (ESI) available: Parameters associated with the single crystal diffraction data, selected bond lengths and angles of **Ir1** and **Ir3**. Electrochemical data, percentage distributions of HOMO/LUMO and the lifetime curves in degassed solution at room temperature of the complexes **Ir1** to **Ir4**. Power efficiency–luminance curves of **DS1/DS2** and **DD1/DD2** devices. PL spectra in neat and doped films of **Ir3** and **Ir4**. CCDC 1535471 and 1535473. For ESI and crystallographic data in CIF or other electronic format see DOI: 10.1039/c7ra05530g



Scheme 1 Synthetic routes of ligands and complexes.

Ir(III) complexes with 2,3-diphenylquinoxaline (DPQ) derivatives as main ligands were reported to emit saturated red or deep red phosphorescence, but their electroluminescent performances were unsatisfactory.<sup>6</sup> In this work, we synthesized four deep red Ir(III) complexes using DPQ derivatives as main ligands with or without fluorine (F) substituted on different positions of phenyl or quinoxaline rings. The lower vibrational frequency of C–F bonds can reduce the rate of nonradioactive deactivation, which will enhance the photoluminescence quantum yields (PLQYs).<sup>7</sup> 1,3,4-Oxadiazole derivatives with good electron affinity are introduced as the ancillary ligands, which will improve the electron transport ability of Ir(III) complexes, resulting in better balance of charge transport, contributing to high device efficiency and low efficiency roll-off.<sup>8</sup> The molecular structures of ligands and complexes are shown in Scheme 1.

## Results and discussion

### Preparation and X-ray crystallography

Scheme 1 shows the synthetic routes of the ligands and Ir(III) complexes. The cyclometallated ligand **L1** was purchased, while the ligands **L2**, **L3** and **L4** were synthesized *via* a condensation reaction from benzil and 1,2-diaminobenzene. The ancillary ligand 2-(5-phenyl-1,3,4-oxadiazol-2-yl)phenol (**HPOP**) and potassium salt (**KPOP**) were prepared according to our previous publications.<sup>8</sup> The complexes were obtained in two steps with popular methods *via* Ir(III) chloro-bridged dimer.<sup>6</sup> Purification of the mixture by silica gel chromatography provided crude products (**Ir1–Ir4**), which were further purified by vacuum sublimation. All the new compounds were fully characterized by <sup>1</sup>H NMR, <sup>13</sup>C NMR, <sup>19</sup>F NMR, the electrospray ionization mass spectra (ESI-MS), the high resolution electrospray ionization mass spectra (HR ESI-MS) and elemental analyses. The crystal structures of **Ir1** and **Ir3** further confirmed the identity of the complexes.

Fig. 1 shows the Oak Ridge Thermal Ellipsoidal Plot (ORTEP) diagrams of **Ir1** and **Ir3** single crystals, the corresponding crystallographic data are summarized in Table S1 (ESI<sup>†</sup>), and the selected bond lengths and angles are listed in Table S2 (ESI<sup>†</sup>). The iridium centre adopts a distorted octahedral coordination geometry with two C<sup>^</sup>N cyclometalated ligands and

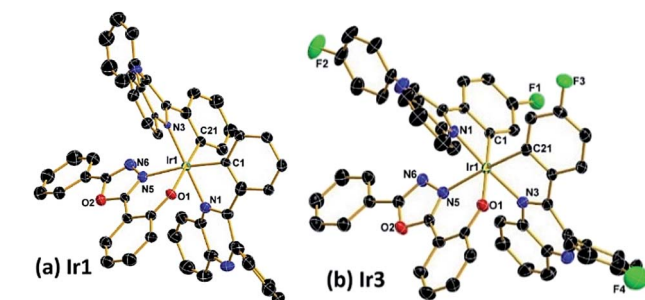


Fig. 1 Oak Ridge Thermal Ellipsoidal Plot (ORTEP) diagrams of the complexes (a) **Ir1** (CCDC no. 1535471); (b) **Ir3** (CCDC no. 1535473<sup>†</sup>). Hydrogen atoms are omitted for clarity. Ellipsoids are drawn at 30% probability level.

one monoanionic bidentate N<sup>^</sup>O ancillary ligand. Apparently, the phenyl rings of the main ligands which do not chelate with the iridium atom are not coplanar with the cyclometalated ligands in order to reduce the steric hindrance. Concerning the POP ancillary ligand with three rings, the phenol ring and the oxadiazole ring chelate with the iridium centre *via* the O atom and an N atom, respectively, forming a relatively rigid hexatomic coordination ring. The Ir–C and Ir–N bonds between the Ir centre and the C<sup>^</sup>N main ligands are around 2.0 Å, while the Ir–N and Ir–O bonds between the Ir atom and the ancillary ligand are in the range of 2.14–2.18 Å. Moreover, the C–C and C–N bond lengths and angles are in agreement with the corresponding parameters described in other similarly constituted Ir(III) complexes.<sup>6,8</sup>

### Thermal stability

The thermal stability of emitters is very important for high quality OLEDs. Complexes that are suitable for OLED application should have high enough melting points and decomposition temperatures to be deposited onto the solid face and survive long periods of application without any decomposition. The thermal properties of the complexes were characterized by different scanning calorimetry (DSC) and thermogravimetric (TG) measurements under a nitrogen steam. The DSC curves in Fig. 2(a) give the melting points ( $T_m$ ) of **Ir1**, **Ir2**, **Ir3** and **Ir4** as high as 386 °C, 370 °C, 389 °C and 370 °C, respectively. From the TG curves in Fig. 2(b), it can be seen that the decomposition temperature ( $T_d$ , 5% loss of weight) is 411 °C for **Ir1**, 402 °C for **Ir2**, 401 °C for **Ir3** and 397 °C for **Ir4**, respectively. Consequently,

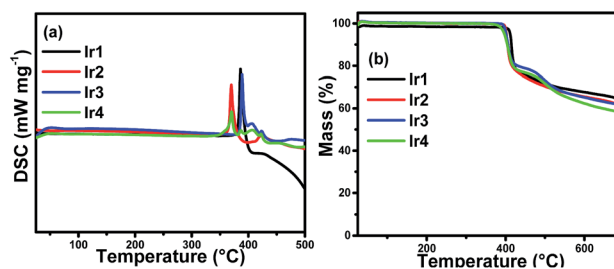


Fig. 2 DSC (a) and TG (b) thermograms of the complexes.



all complexes can be vacuum evaporated without decomposition, indicating that all the complexes are potential emitting materials for the fabrication of stable OLEDs.

### Photophysical property

The UV-vis molar absorptivity spectra of the complexes in degassed  $\text{CH}_2\text{Cl}_2$  at  $5 \times 10^{-5} \text{ mol L}^{-1}$  are shown in Fig. 3(a) and the photophysical data are listed in Table 1. The intense bands in the range of 250–350 nm are assigned to the spin-allowed ligand-centered  $^1\text{LC}$  ( $\pi-\pi^*$ ) transition of the cyclometalated and ancillary ligands. The relatively weak absorption bands at lower energies extending into the spectral region (350–550 nm) are ascribed to the mixing of the spin-allowed singlet metal-to-ligand charge-transfer ( $^1\text{MLCT}$ ), triplet metal-to-ligand charge-transfer ( $^3\text{MLCT}$ ) states or LLCT (ligand-to-ligand charge-transfer) transition through strong spin-orbit coupling of iridium atoms.<sup>9</sup> From Fig. 3(a) and Table 1 it can be observed that there is no obvious distinction among the absorption spectra of the complexes **Ir2** to **Ir4**, which are red-shifted slightly compared with that of **Ir1**, suggesting that fluorination on the main ligands has mild effect on the absorption spectra of the iridium complexes.

Photoluminescence (PL) spectra of the complexes in degassed  $\text{CH}_2\text{Cl}_2$  solutions at room temperature are depicted in Fig. 3(b), and the relevant data are summarized in Table 1. The excitation wavelength for the PL spectra of **Ir1**–**Ir4** is 378 nm, 387 nm, 388 nm and 391 nm, respectively. The complexes

emitted deep red phosphorescence ranging from 634 nm to 650 nm. It is obvious that the PL spectra of **Ir3** and **Ir4** exhibit a hypsochromic shift compared with **Ir1**, which suggests the fluorine substituted on the phenyl rings of the main ligands (DPQ) can affect the emission spectra significantly. Meanwhile, the PL spectrum of **Ir2** is red-shifted mildly indicating that fluoro-substituents on the quinoxaline moiety have slight influence on the emission spectra of the Ir(III) complexes, which can be also detected from the comparison between the PL spectra of **Ir3** and **Ir4**.

Additionally, the PL quantum yields (PLQYs) of **Ir1** to **Ir4** are 24.8%, 18.3%, 31.2% and 40.6%, respectively. The complex **Ir4** with fluorination on both the phenyl and quinoxaline rings of the main ligands achieves the highest PLQY, and the PLQY of the complex **Ir3** which has fluoro-substituted on the phenyl rings is higher than that of **Ir1** with none fluoro-substituents. The results demonstrate that fluorination can enhance the PLQYs of iridium(III) complexes, for the reason that the C–F bond can reduce the rate of nonradioactive deactivation. Thus, the complex **Ir4** with fluorine substituted on both phenyl and quinoxaline rings of the main ligand shows the highest PLQY among these complexes. In contrast, the complex **Ir2** has lower PLQY than **Ir1**. In general, the position and number of fluoro-substituents can affect not only the PL spectra of the Ir(III) complexes but also the PLQYs. Furthermore, the phosphorescence lifetime ( $\tau$ ) is an important factor that affects the rate of triplet–triplet annihilation (TTA) in OLEDs. Longer  $\tau$  values usually cause greater TTA effect.<sup>10</sup> The phosphorescence lifetimes of the four complexes are in the range of microseconds (1.83–1.98  $\mu\text{s}$ ) at room temperature and are indicative of the phosphorescence origins from triplet metal-to-ligand charge-transfer ( $^3\text{MLCT}$ ) and/or triplet ligand-to-ligand charge-transfer ( $^3\text{LLCT}$ ) states. To better understand the emission properties of the four complexes, the radiative ( $k_r$ ) and non-radiative ( $k_{nr}$ ) constants are calculated and summarized in Table 1. The complex **Ir4** with the highest PLQY has the highest  $k_r$  value ( $2.05 \times 10^5 \text{ s}^{-1}$ ), the  $k_r$  value of the complex **Ir2** with the deepest red emission and the lowest PLQY is as low as  $9.89 \times 10^4 \text{ s}^{-1}$ . The  $k_{nr}$  values increase as the maximum peak shifts to the deep red region, the deep red emitter **Ir2** has the highest  $k_{nr}$  as  $4.41 \times 10^5 \text{ s}^{-1}$ . The low PLQY of the complex **Ir2** is partly

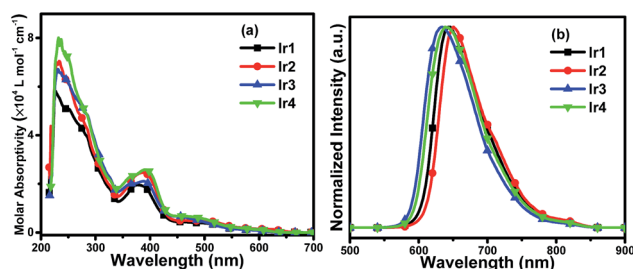


Fig. 3 (a) UV-vis molar absorptivity and (b) normalized emission spectra of **Ir1**, **Ir2**, **Ir3** and **Ir4** in degassed  $\text{CH}_2\text{Cl}_2$  solutions ( $5 \times 10^{-5} \text{ mol L}^{-1}$ ) at room temperature.

Table 1 Physical properties of the complexes **Ir1**, **Ir2**, **Ir3** and **Ir4**

Complex	$T_s/T_m/T_d^a$ ( $^{\circ}\text{C}$ )	$\lambda_{\text{abs}}^b$ (nm) [ $\epsilon^c$ ( $10^4 \text{ L mol}^{-1} \text{ cm}^{-1}$ )]	$\lambda_{\text{em}}^d$ (nm)	$\Phi^e$ (%)	$\tau^f$ ( $\mu\text{s}$ )	HOMO/LUMO <sup>g</sup> (eV)	$k_r^h$ ( $10^5 \text{ s}^{-1}$ )	$k_{nr}^h$ ( $10^5 \text{ s}^{-1}$ )
<b>Ir1</b>	365/386/411	227 (5.81)/378 (1.96)	645	24.8	1.86	−5.26/−3.46	1.33	4.04
<b>Ir2</b>	350/370/402	233 (7.06)/387 (2.47)	650	18.3	1.85	−5.36/−3.60	0.99	4.41
<b>Ir3</b>	350/389/401	231 (6.72)/388 (2.11)	634	31.2	1.83	−5.33/−3.44	1.70	3.76
<b>Ir4</b>	340/370/397	232 (8.01)/391 (2.59)	639	40.6	1.98	−5.45/−3.57	2.05	3.00

<sup>a</sup>  $T_s$ : sublimation temperature at  $2.0 \times 10^{-4} \text{ Pa}$ ,  $T_m$ : melting temperature,  $T_d$ : decomposition temperature. <sup>b</sup> Measured in degassed  $\text{CH}_2\text{Cl}_2$  solution at a concentration of  $5 \times 10^{-5} \text{ mol L}^{-1}$  at room temperature. <sup>c</sup> Molar absorptivity. <sup>d</sup> Measured in degassed  $\text{CH}_2\text{Cl}_2$  solution at a concentration of  $5 \times 10^{-5} \text{ mol L}^{-1}$  at 298 K. <sup>e</sup> Measured in degassed  $\text{CH}_2\text{Cl}_2$  solution at room temperature using  $[\text{Ru}(\text{bpy})_3]\text{Cl}_2$  as the standard sample ( $\Phi = 0.028$ ). <sup>f</sup> Measured in degassed  $\text{CH}_2\text{Cl}_2$  solution at a concentration of  $5 \times 10^{-5} \text{ mol L}^{-1}$  at room temperature. <sup>g</sup> From the onset of oxidation potentials of the cyclic voltammetry (CV) diagram using ferrocene as the internal standard in deaerated  $\text{CH}_2\text{Cl}_2$  and the optical energy gap from the absorption spectra. <sup>h</sup> Radiative ( $k_r$ ) and non-radiative ( $k_{nr}$ ) constants are calculated according to the equations:  $k_r = \Phi/\tau$  and  $k_{nr} = 1/\tau - k_r$ .



ascribed to the decrease of radiative transition and the increase of nonradioactive transition.

### Electrochemical properties and theoretical calculations

The redox properties, highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) energy levels of the dopants are relative to the charge transport ability and the OLED structure. To study these properties and calculate the HOMO/LUMO levels of the complexes, the electrochemical properties of **Ir1**–**Ir4** were measured by cyclic voltammetry in deaerated dichloromethane using ferrocene as the internal standard (Fig. 4(a)). The HOMO levels were calculated from the oxidation peak potential ( $E_{\text{ox}}$ ) and the energy gap ( $E_g$ ) was calculated from the UV-vis absorption edges.<sup>11</sup> Then the LUMO levels were determined according to the equation  $\text{LUMO} = \text{HOMO} + E_g$ . The electrochemical data are collected in Table S3 (ESI†). The cyclic voltammograms of the complexes in the positive range show obvious oxidation peaks, while the reduction peaks are negligible, demonstrating that the redox process of the complexes is not completely reversible, which is also observed in similar Ir(III) complexes containing 1,3,4-oxadiazole units.<sup>8</sup> In the negative scan range, the complexes exhibit quasi-reversible redox process, which mainly occurs on the stronger electron-accepting heterocyclic portion of the cyclometalated ligands. Notably, the complexes **Ir2**, **Ir3** and **Ir4** show higher oxidation potentials than that of **Ir1**, which is ascribed to the electronegative effect of the fluorine making the complexes more difficult to lose electron, leading to lower HOMO levels. On the other hand, the reduction potential is decreased by the introduction of F atoms, resulting in a lower LUMO level, which

is conducive to the injection and capture of electrons in the OLEDs. The F atoms in the main ligands decrease the HOMO/LUMO levels of the complexes leading to different  $E_g$  of the complexes which contributes to the variations in the PL spectra. The complex **Ir3** with the largest  $E_g$  (1.89 eV) among all the complexes emits phosphorescence with the maximum peak at 634 nm. Whereas, the complex **Ir2** has the smallest  $E_g$  (1.76 eV), which exhibits the deepest red emission peaking at 650 nm. These phenomena suggest that fluorination on the quinoxaline ring of the main ligands will reduce the energy gap of the Ir(III) complexes resulting in a bathochromic shift of the emission spectra.

To provide further study on the electronic structures of the complexes, theoretical calculations were performed on optimized geometries in  $\text{CH}_2\text{Cl}_2$ . The calculations on the ground electronic states of the complexes were carried out using density functional theory (DFT) and time-dependent DFT (TD-DFT) at the B3LYP level.<sup>12</sup> The basis set used for C, H, N, O and F atoms was 6-31G(d,p) while the LanL2DZ basis set was used for Ir atoms.<sup>13</sup> The solvent effect of  $\text{CH}_2\text{Cl}_2$  was taken into consideration using conductor-like polarizable continuum model (C-PCM).<sup>14</sup> All these calculations were performed with Gaussian 09.<sup>15</sup> The QMForge program was used to give accurate percentage data of the frontier molecular orbitals (FMOs).<sup>16</sup> Contour plots of FMOs are shown in Fig. 4(c). The energies and percentage composition of ligands and metal orbitals are listed in Table S4 (ESI†). The results are helpful for the assignment of the electron transition characteristics and the discussion on the photophysical variations. For these complexes, the LUMOs are mainly localized on the main ligands (94.55–94.80%) with minor contributions from Ir d orbitals (3.47–3.69%) and the ancillary ligand (1.69–1.81%). Interestingly, the locations of the HOMOs on the POP ligands are over 75% for the four complexes (75.27–77.79%), while the compositions on the d orbitals of Ir atoms and the main ligands are in the range of 14.17–15.86% and 8.04–8.87%, respectively. The rising compositions of HOMOs on the ancillary ligands make the electrochemical oxidation processes occur on both metal centered orbitals and ancillary ligands, leading to the irreversible redox processes of the Ir(III) complexes. Compared with the complex **Ir1**, the orbital distributions of LUMOs for **Ir2**, **Ir3** and **Ir4** have more contributions from the main ligands and less from Ir d orbitals. The calculation results indicate that the fluorination affects the orbital distributions and the HOMO/LUMO levels of the Ir(III) complexes.

### Electron mobility

As the hole mobility is roughly 2–3 orders of magnitude higher than the electron mobility in OLEDs,<sup>17</sup> their excitation lifetime relies on the electron transport capability. The good electron mobility of the phosphorescent emitters would facilitate the injection and transport of electrons, which will broaden the recombination zone, balance the distribution of hole–electron and reduce leakage current, leading to suppressed TTA and triplet–polaron annihilation (TPA) effects, improved recombination probability, high device efficiency, and low efficiency

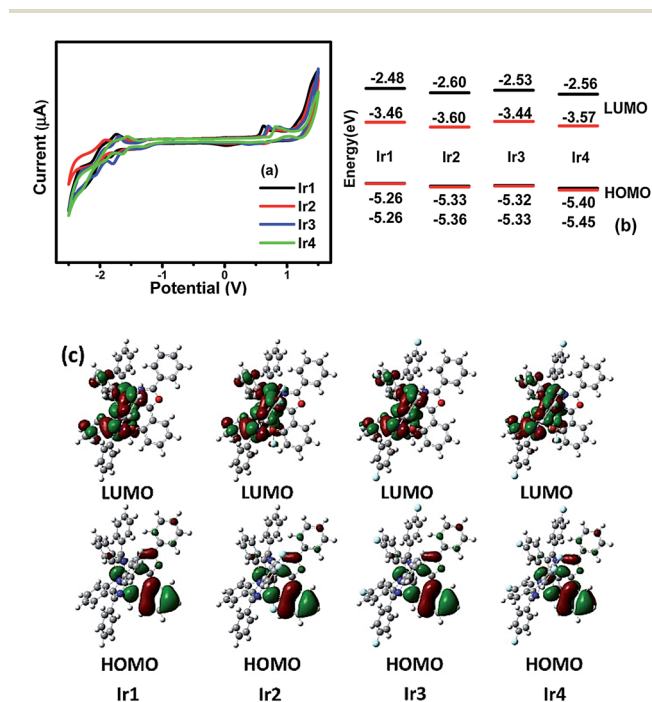


Fig. 4 (a) Cyclic voltammogram curves, (b) theoretical (black) and experimental (red) energy levels and (c) contour plots of HOMO/LUMO of **Ir1** to **Ir4**.





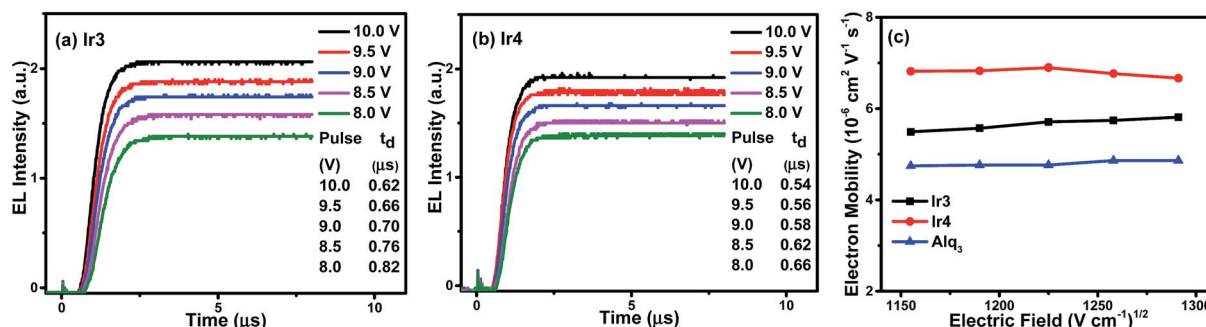


Fig. 5 The transient EL signals for the device structure of ITO/TAPC (50 nm)/Ir3 (a) or Ir4 (b) (60 nm)/LiF (1 nm)/Al (100 nm) under different applied fields, and (c) the electric field dependence of charge electron mobility in the thin films of Ir3, Ir4 and Alq3.

roll-off.<sup>18</sup> As discussed before, introducing 1,3,4-oxadiazole derivatives with good electron affinity may improve the electron mobility of the complexes, which would suppress the TPA effects effectively and obtain phosphorescent OLEDs with low efficiency roll-off.

To measure the electron mobility of the complexes, we conducted the transient electroluminescence (TEL) measurement based on the device of ITO (indium tin oxide)/TAPC (di-[4-(*N,N*-ditolyl-amino)-phenyl]cyclohexane, 50 nm)/Ir3 or Ir4 (60 nm)/LiF (1 nm)/Al (100 nm).<sup>19</sup> The TAPC is the hole-transport layer, whereas the Ir(III) complexes perform as both the emissive and electron-transport layers. To check the accuracy of our measurements, we also measured the electron mobility of Alq3 (tris-(8-hydroxyquinoline)aluminum), which is the typically well-known electron transport material, whose electron mobility has been reported in many references.<sup>20</sup> The experimental results (Fig. 5) show that the electron mobility in 60 nm Ir3 and Ir4 layers are between  $5.49\text{--}5.81 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  and  $6.67\text{--}6.90 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ , respectively, under an electric field from  $1150 (\text{V cm}^{-1})^{1/2}$  to  $1300 (\text{V cm}^{-1})^{1/2}$ , while that of Alq3 is between  $4.74\text{--}4.86 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . From Fig. 5(c) it can also be observed that Ir3 and Ir4 complexes have higher electron mobility than that of Alq3. The good electron transport ability of Ir3 and Ir4 will facilitate the injection and transport of electrons, which broadens the recombination zone and balances the distribution of holes and electrons, particularly for high doping concentrations. Therefore, efficient OLEDs with suppressed efficiency roll-off are expected.

## OLED performance

To evaluate the electroluminescent performances of these complexes, the complexes Ir3 and Ir4 with higher PLQYs (31.2% and 40.6%, respectively) were selected to fabricate single emitting layer (EML) devices DS1 and DS2 with the structure of ITO/MoO3 (molybdenum oxide, 5 nm)/TAPC (30 nm)/26DCzPPy (2,6-bis(3-(carbazol-9-yl)phenyl)pyridine): Ir3 or Ir4 (2 wt%, 10 nm)/TmPyPB (1,3,5-tri(*m*-pyrid-3-yl-phenyl)benzene, 40 nm)/LiF (1 nm)/Al (100 nm). MoO3 and LiF served as hole- and electron-injecting interface modified materials, respectively. TAPC, which has high hole mobility ( $1 \times 10^{-2} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ ) and high-lying LUMO level ( $-2.0 \text{ eV}$ ), was used as the hole transport/electron block layer (HTL/EBL),<sup>21</sup> while TmPyPB with high

electron mobility ( $1 \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ ) and low-lying HOMO level ( $-6.7 \text{ eV}$ ) was used as the electron transport/hole block layer (ETL/HBL).<sup>22</sup> The bipolar material 26DCzPPy was chosen as the host because its electron mobility ( $\mu_e$ ) and hole mobility ( $\mu_h$ ) values are nearly equal ( $1\text{--}8 \times 10^{-5} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  at an electric field between  $6.0 \times 10^5$  and  $1.0 \times 10^6 \text{ V cm}^{-1}$ ), which benefits the electron-hole balance in the EML.<sup>23</sup> The material chemical structures, as well as the device structure and energy level diagrams, are depicted in Fig. 6. Apparently, the HOMO/LUMO levels of the Ir3 and Ir4 calculated from the CV curves are within those of 26DCzPPy, thus, carriers are expected to transport easily between layers and excellent carrier trapping would be the main mechanism in the devices.<sup>24</sup> Notably, carriers would be well confined and recombined within the EML. The EL spectra, current density-luminance-voltage, current efficiency-luminance and external quantum efficiency-luminance characteristics of all the devices are shown in Fig. 7. The key EL data are summarized in Table 2.

Both the single-EML devices DS1 and DS2 exhibit typical emissions with peak maxima at 637 and 638 nm, respectively, in accordance with the PL spectra of Ir3 and Ir4 in the solution. The CIE (Commission Internationale de l'Eclairage) coordinates operated at 8 V are corresponded to the deep red region ((0.686, 0.314) for DS1 and (0.687, 0.312) for DS2). Apart from the characteristic emission of the Ir complexes, the devices displayed weak emission ranging from 350–500 nm, which originates from the host 26DCzPPy and is attributed to the

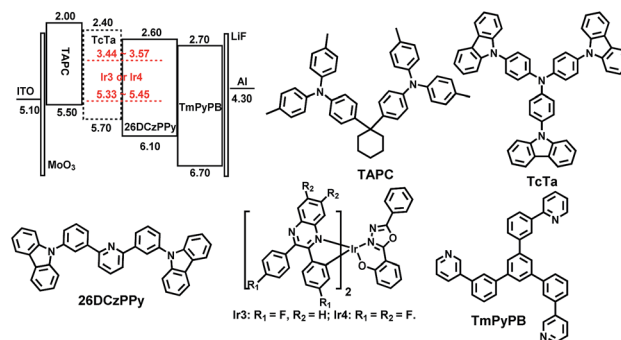


Fig. 6 Energy level diagrams of HOMO and LUMO levels (relative to vacuum level) for materials investigated in this work and their molecular structures.

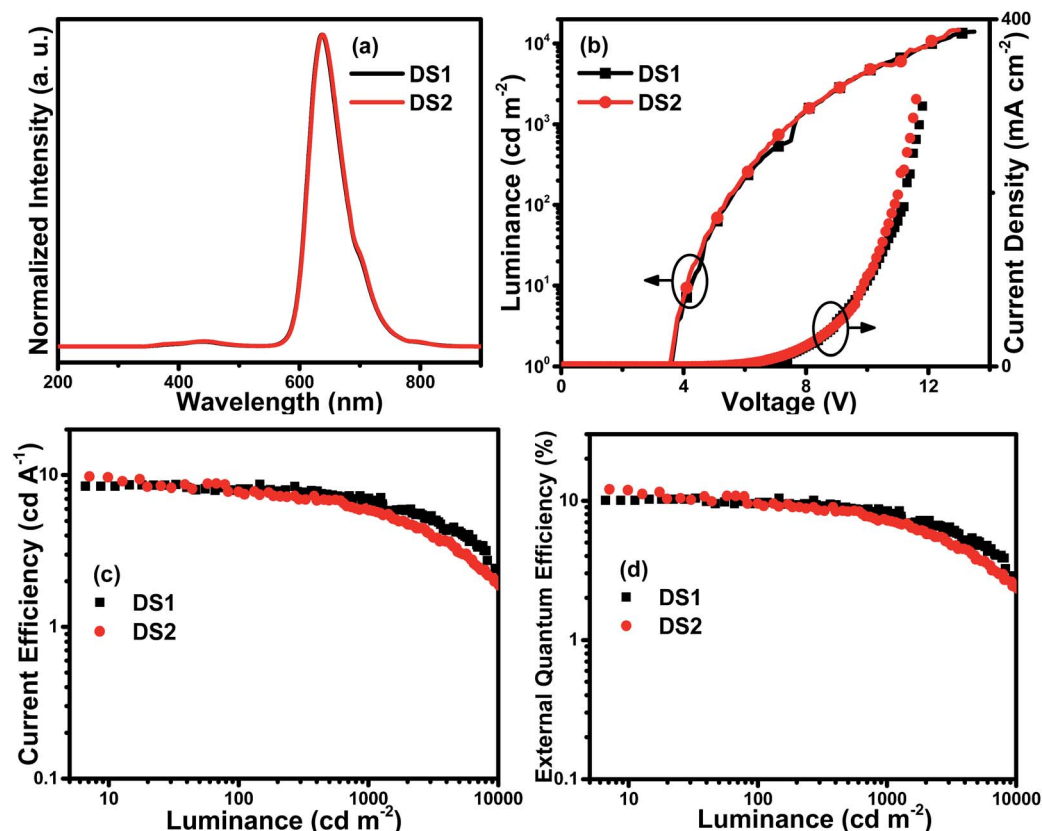


Fig. 7 Characteristics of single-EML devices **DS1** and **DS2**: (a) normalized EL spectra at 8 V; (b) current density–luminance–voltage ( $J$ – $L$ – $V$ ) curves; (c) current efficiency–luminance ( $\eta_c$ – $L$ ) curves and (d) external quantum efficiency–luminance (EQE– $L$ ) curves.

Table 2 EL performances of single-EML devices **DS1** and **DS2** and double-EMLs devices **DD1** and **DD2**

Device	Emitter	$V_{\text{turn-on}}^a$ (V)	$L_{\text{max}}^b$ [cd m $^{-2}$ (V)]	$\eta_{c,\text{max}}^c$ (cd A $^{-1}$ ) (EQE $_{\text{max}}^d$ )	$\eta_{c,L1000}^e$ (cd A $^{-1}$ ) (EQE $_{L1000}^f$ )	$\eta_{p,\text{max}}^g$ (lm W $^{-1}$ )	$\lambda_{\text{max}}^h$ (nm)	CIE $^i$ (x, y)
<b>DS1</b>	<b>Ir3</b>	3.6	14 044 (13.5)	8.7 (10.1%)	7.1 (8.5%)	6.6	637	0.686, 0.314
<b>DS2</b>	<b>Ir4</b>	3.6	14 768 (13.0)	9.8 (12.1%)	5.9 (7.2%)	7.7	638	0.687, 0.312
<b>DD1</b>	<b>Ir3</b>	3.7	18 503 (13.1)	11.9 (15.0%)	9.4 (11.9%)	10.1	638	0.689, 0.311
<b>DD2</b>	<b>Ir4</b>	3.5	20 676 (12.7)	14.0 (17.8%)	8.9 (11.4%)	12.0	639	0.689, 0.311

<sup>a</sup> Turn-on voltage recorded at a luminance of 1 cd m $^{-2}$ . <sup>b</sup> Maximum luminance. <sup>c</sup> Maximum current efficiency. <sup>d</sup> Maximum external quantum efficiency (EQE). <sup>e</sup> Current efficiency at 1000 cd m $^{-2}$ . <sup>f</sup> EQE at 1000 cd m $^{-2}$ . <sup>g</sup> Maximum power efficiency. <sup>h</sup> Values were collected at 8 V.

<sup>i</sup> Commission Internationale de l'Eclairage coordinates (CIE) at 8 V.

accumulation of holes and electrons within the EML implying that few holes and electrons recombine on the host molecules. From Fig. 7 and Table 2, it can be seen that the single-EML device **DS2** using **Ir4** as the emitter shows better EL performances with the maximum luminance ( $L_{\text{max}}$ ), current efficiency ( $\eta_{c,\text{max}}$ ), power efficiency ( $\eta_{p,\text{max}}$ ) and external quantum efficiency (EQE $_{\text{max}}$ ) of up to 14 768 cd m $^{-2}$ , 9.8 cd A $^{-1}$ , 7.7 lm W $^{-1}$  and 12.1%, respectively. This is due to the high electron mobility of **Ir4** as well as the low-lying LUMO level which is beneficial for the electron transport and trapping in the EML. These results indicate that fluorine on both the phenyl rings and the quinoxaline ring of the main ligand will enhance the EL performances of the Ir(III) complexes. However, the efficiency

roll-off ratios of the devices **DS1** and **DS2** are apparent as the luminance rises. For example, the current efficiency and EQE of the device **DS2** decline to 5.9 cd A $^{-1}$  and 7.2%, respectively, at the luminance of 1000 cd m $^{-2}$ . In the single-EML devices, hole–electron recombination and exciton accumulation are expected near the interface of the EML (26DCzPPy: Ir complexes) and ETL (TmPyPB) leading to serious TTA/TPA effects and consequently high efficiency roll-off as the current density rises. Subsequently, more devices with double EMLs were prepared and investigated, which would broaden the recombination zone of holes and electrons in result of more balanced hole–electron recombination and better energy transport from the host to the dopant.



To further improve the EL performances of the complexes, double-EML devices named as **DD1** and **DD2**, respectively, with the configuration of ITO/MoO<sub>3</sub> (5 nm)/TAPC (30 nm)/TcTa (4,4',4''-tris(carbazol-9-yl) triphenylamine): **Ir3** or **Ir4** (2 wt%, 10 nm)/26DCzPPy: **Ir3** or **Ir4** (2 wt%, 10 nm)/TmPyPB (40 nm)/LiF (1 nm)/Al (100 nm) were also fabricated. The widely used p-type material TcTa was added as another host material which would also lower the HOMO energy barrier between TAPC and 26DCzPPy due to its matched HOMO level (−5.70 eV, Fig. 6).<sup>25</sup> The EL characteristics of these devices are depicted in Fig. 8 and the key EL data are collected in Table 2 as well.

From the EL spectra in Fig. 8(a), it can be observed that both the double-EML devices exhibit deep red emission with the maximum peaks at 638 nm and 639 nm, respectively, which is also proved by the CIE coordinates. Additionally, there is no obvious distinction compared with the EL spectra (Fig. 7(a)) of the single-EML devices and the PL spectra of the complexes in solution (Fig. 3(b)). Weak emission in the range of 350–500 nm was observed in the EL spectra of double-EML devices caused by the emission of TcTa peaked at 385 nm. One reason is that TcTa is well-known as a kind of hole transport material, within the layer the imbalanced distribution of holes and electrons will cause the recombination of excitons on the TcTa molecules. Compared with the single-EML devices, both the double-EML devices display better EL performances with lower efficiency roll-off. The device **DD2** with the **Ir4** dopant has the best

performances with the  $L_{\max}$ ,  $\eta_{\text{c,max}}$ ,  $\eta_{\text{p,max}}$  and  $\text{EQE}_{\max}$  of 20 676  $\text{cd m}^{-2}$ , 14.0  $\text{cd A}^{-1}$ , 12.0  $\text{lm W}^{-1}$  and 17.8%, respectively. Furthermore, the efficiency roll-off of both double-EML devices is restrained. For instance, the  $\eta_{\text{c}}$  and EQE of the device **DD1** can be retained as 9.4  $\text{cd A}^{-1}$  and 11.9%, respectively, when the luminance rises to 1000  $\text{cd m}^{-2}$ . Compared with single-EML devices, double-EML devices possess improved hole injection ability from HTL into EMLs because the HOMO level of TcTa situates between those of TAPC and 26DCzPPy, thus causing the low hole injection barrier. Consequently, double-EML devices obtained better balance of carriers within EMLs, wider recombination zone and lower densities of excitons within EMLs, thus realizing higher luminance and efficiency as well as slighter efficiency roll-off.

Compared with the Ir(III) complexes with the same cyclo-metallated ligands and tetraphenylimidodiphosphinate (tpip) as the ancillary ligand in our recent work ( $L_{\max}$ : 25 926  $\text{cd m}^{-2}$ ,  $\eta_{\text{c,max}}$ : 16.6  $\text{cd A}^{-1}$ ,  $\eta_{\text{p,max}}$ : 13.7  $\text{lm W}^{-1}$ ,  $\text{EQE}_{\max}$ : 19.9%),<sup>26</sup> the devices with **Ir3** and **Ir4** as the emitters exhibit lower performances, because tpip ligands can improve the charge transport ability of the complexes and suppress TTA and TPA effects more efficiently. But the OLED performances are better than other Ir(III) complexes with similar 2,3-diphenylquinoxaline (DPQ) derivatives as main ligands,<sup>7</sup> which is due to the high electron mobility realized by the introduction of 1,3,4-oxadiazole derivatives (POP) with good electron affinity as the ancillary ligands.

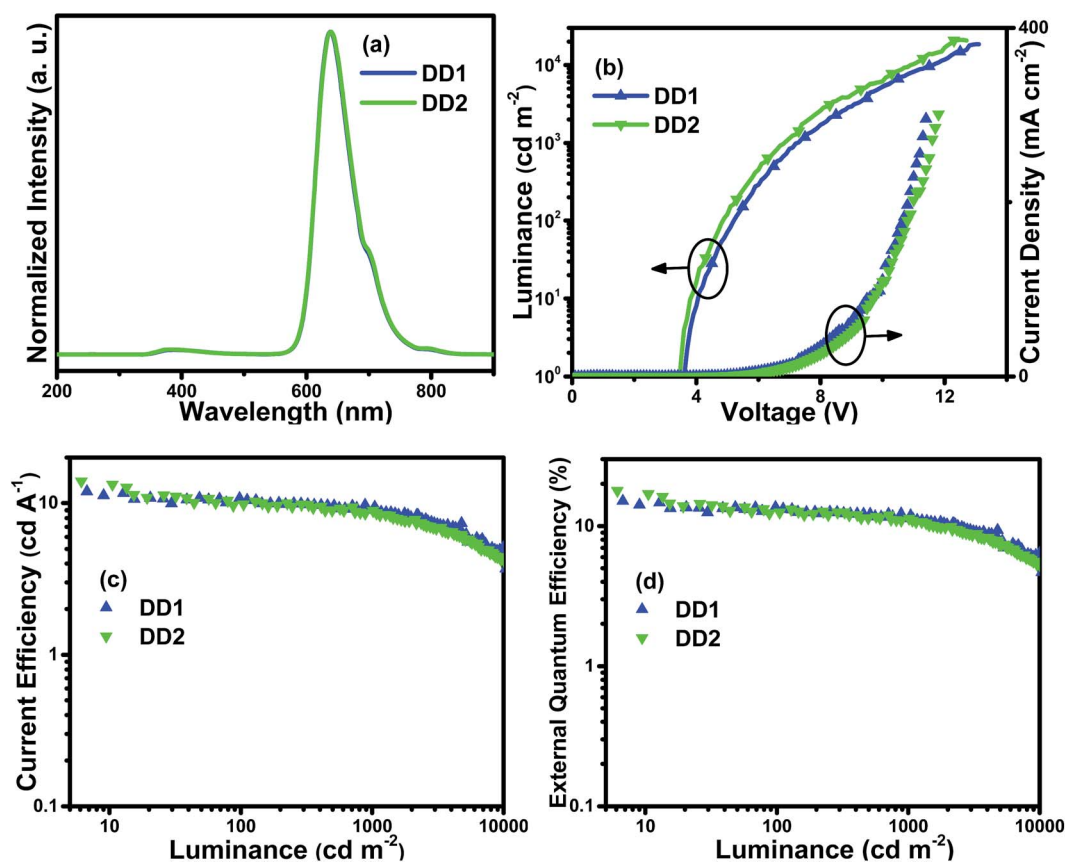


Fig. 8 Characteristics of double-EML devices DD1 and DD2: (a) normalized EL spectra at 8 V; (b) current density–luminance–voltage ( $J$ – $L$ – $V$ ) curves; (c) current efficiency–luminance ( $\eta_{\text{c}}$ – $L$ ) curves and (d) external quantum efficiency–luminance (EQE– $L$ ) curves.



The complex **Ir4** with fluoro-substituted on both phenyl and quinoxaline rings of the main ligands has better OLED performances than **Ir3** with fluoro-substituted only on the phenyl rings, which is attributed to the higher electron mobility and PLQY. The results indicate that fluoro-substituents in the main ligands and the POP ancillary ligand with good electron affinity can improve the electron mobility of the Ir(III) complexes and suppress TTA and TPA effects, resulting in the significant OLED performances.

## Conclusions

In conclusion, four novel Ir(III) complexes containing 2,3-diphenylquinoxaline derivatives with or without fluoro-substituents on different positions as the main ligands and 2-(5-phenyl-1,3,4-oxadiazol-2-yl)phenol as the ancillary ligand were thoroughly characterized. All the complexes emit deep red phosphorescence. The complexes **Ir3** and **Ir4** have higher electron mobility than that of the typical electron transport material Alq<sub>3</sub>. Compared with the single-EML devices, the double-EML devices with the complexes **Ir3** or **Ir4** as the emitter display better EL performances and lower efficiency roll-off. The double-EML device **DD2** using the **Ir4** dopant with four F atoms in the main ligands exhibits the best performances with the maximum luminance, current efficiency, power efficiency and external quantum efficiency of 20 676 cd m<sup>-2</sup>, 14.06 cd A<sup>-1</sup>, 12.0 lm W<sup>-1</sup> and 17.8%, respectively. The results suggest that the positions of fluoro-substitution can affect the photophysical properties and the EL performances of the iridium complexes. These Ir(III) complexes are potential deep red phosphorescent materials for specific applications of OLEDs.

## Experimental section

### General information

<sup>1</sup>H and <sup>19</sup>F NMR spectra were measured on a Bruker AM 500 spectrometer. Electrospray ionization mass spectra (ESI-MS) were obtained with ESI-MS (LCQ Fleet, Thermo Fisher Scientific). The high resolution electrospray ionization mass spectra (HR ESI-MS) were recorded on an Agilent 6540 UHD Accurate-Mass Q-TOF LC/MS. Elemental analyses for C, H and N were performed on an Elementar Vario MICRO analyzer. TG-DSC measurements were carried out on a DSC 823e analyzer (METTLER). UV-vis absorption and photoluminescence spectra were measured on a Shimadzu UV-3100 and a Hitachi F-4600 spectrophotometer at room temperature, respectively. The luminescence quantum efficiency was calculated by a comparison of a standard sample [Ru(bpy)<sub>3</sub>]Cl<sub>2</sub> in degassed CH<sub>2</sub>Cl<sub>2</sub> solutions of 5 × 10<sup>-5</sup> mol L<sup>-1</sup>.<sup>27</sup> Cyclic voltammetry measurements were conducted on a MPI-A multifunctional electrochemical and chemiluminescent system at room temperature, with a polished Pt plate as the working electrode, platinum thread as the counter electrode and Ag-AgNO<sub>3</sub> (0.1 M) in CH<sub>3</sub>CN as the reference electrode, tetra-*n*-butylammonium hexafluorophosphate (0.1 M) was used as the supporting electrolyte using Fc<sup>+</sup>/Fc as the internal standard and scan rate of 0.05 V s<sup>-1</sup> in deaerated dichloromethane.

### X-ray crystallography

X-ray crystallographic measurements of the single crystals were carried out on a Bruker SMART CCD diffractometer (Bruker Daltonic Inc.) using monochromated Mo K $\alpha$  radiation ( $\lambda$  = 0.71073 Å) at room temperature. Cell parameters were retrieved using SMART software and refined using SAINT<sup>28</sup> program in order to reduce the highly redundant data sets. Data were collected using a narrow-frame method with scan width of 0.30° in  $\omega$  and an exposure time of 5 s per frame. Absorption corrections were applied using SADABS<sup>29</sup> supplied by Bruker. The structures were solved by Patterson methods and refined by full-matrix least-squares on  $F^2$  using the program SHELXS-2014.<sup>30</sup> The positions of metal atoms and their first coordination spheres were located from direct-methods E-maps, other non-hydrogen atoms were found in alternating difference Fourier syntheses and least-squares refinement cycles and during the final cycles refined anisotropically. Hydrogen atoms were placed in calculated position and refined as riding atoms with a uniform value of  $U_{iso}$ .

### OLEDs fabrication and measurement

All OLEDs were fabricated on the pre-patterned ITO-coated glass substrate with a sheet resistance of 15  $\Omega$  sq<sup>-1</sup>. The deposition rate for organic compounds is 1–2 Å s<sup>-1</sup>. The phosphor and host were co-evaporated from two separate sources. The cathode consisting of LiF/Al was deposited by evaporation of LiF with a deposition rate of 0.1 Å s<sup>-1</sup> and then by evaporation of Al metal with a rate of 3 Å s<sup>-1</sup>. The effective area of the emitting diode is 0.1 cm<sup>2</sup>. The characteristics of the devices were measured with a computer controlled KEITHLEY 2400 source meter with a calibrated silicon diode in air without device encapsulation. On the basis of the uncorrected PL and EL spectra, the CIE coordinates were calculated using a test program of the spectra scan PR650 spectrophotometer.

### Syntheses

Solvents were carefully dried and distilled from appropriate drying agents prior to use. All reactions were performed under nitrogen. The ligand 2,3-diphenylquinoxaline (**L1**) was purchased and used without further purification. The 2-(5-phenyl-1,3,4-oxadiazol-2-yl)phenol (**HPOP**) ligand and potassium salt (**KPOP**) were prepared according to our previous publications.<sup>8</sup>

**General syntheses of ligands.** Benzil (5.00 mmol) or 4,4'-difluorobenzil (5.00 mmol) was dissolved with 1,2-diamino-4,5-difluoro benzene (5.00 mmol) or *o*-phenylenediamine (5.00 mmol) in 50 mL ethanol, and the solution was refluxed for 24 h. Silica column chromatography purification (petroleum ether : ethyl acetate = 30 : 1) gave white powder for 6,7-difluoro-2,3-diphenylquinoxaline (**L2**), 2,3-bis(4-fluorophenyl)quinoxaline (**L3**) or 6,7-difluoro-2,3-bis(4-fluorophenyl)quinoxaline (**L4**).

**6,7-Difluoro-2,3-diphenylquinoxaline (L2).** 85% yield. <sup>1</sup>H NMR (400 MHz, CDCl<sub>3</sub>)  $\delta$  7.91 (t,  $J$  = 9.3 Hz, 2H), 7.51–7.48 (m, 4H), 7.37 (t,  $J$  = 1.7 Hz, 2H), 7.36 (s, 4H). <sup>13</sup>C NMR (101 MHz, CDCl<sub>3</sub>)  $\delta$  153.77, 151.38, 138.56, 137.30, 129.87, 129.23, 128.45,





114.88.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -129.98 (2F). MS(ESI)  $m/z$  calcd for  $\text{C}_{20}\text{H}_{12}\text{F}_2\text{N}_2$ : 318.10  $[\text{M}]^+$ , found: 319.15  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{20}\text{H}_{12}\text{F}_2\text{N}_2$ : C, 75.46; H, 3.80; N, 8.80. Found: C, 75.50; H, 3.79; N, 8.75. Melting point: 139–141  $^\circ\text{C}$ .

**2,3-Bis(4-fluorophenyl)quinoxaline (L3).** 87% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  8.16 (dd,  $J$  = 6.4, 3.4 Hz, 2H), 7.79 (dd,  $J$  = 6.4 Hz, 3.4 Hz, 2H), 7.51 (dd,  $J$  = 8.9, 5.4 Hz, 4H), 7.06 (t,  $J$  = 8.7 Hz, 4H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  163.30, 152.24, 141.26, 135.07, 131.91, 130.30, 129.22, 115.61.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -111.94 (2F). MS(ESI)  $m/z$  calcd for  $\text{C}_{20}\text{H}_{12}\text{F}_2\text{N}_2$ : 318.10  $[\text{M}]^+$ , found: 319.23  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{20}\text{H}_{12}\text{F}_2\text{N}_2$ : C, 75.46; H, 3.80; N, 8.80. Found: C, 75.45; H, 3.82; N, 8.81. Melting point: 136–138  $^\circ\text{C}$ .

**6,7-Difluoro-2,3-bis(4-fluorophenyl)quinoxaline (L4).** 90% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  7.89 (t,  $J$  = 9.3 Hz, 2H), 7.54–7.44 (m, 4H), 7.11–7.02 (m, 4H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  163.44, 152.68, 152.44, 138.53, 134.48, 131.84, 115.72, 114.81.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -111.31 (2F), -129.30 (2F). MS(ESI)  $m/z$  calcd for  $\text{C}_{20}\text{H}_{10}\text{F}_4\text{N}_2$ : 354.08  $[\text{M}]^+$ , found: 355.16  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{20}\text{H}_{10}\text{F}_4\text{N}_2$ : C, 67.80; H, 2.84; N, 7.91. Found: C, 67.78; H, 2.86; N, 7.89. Melting point: 162–163  $^\circ\text{C}$ .

**General syntheses of iridium complexes.** A mixture of  $\text{IrCl}_3$  (1.00 mmol) and **L1–L4** (2.05 mmol) in 2-ethoxyethanol and water (20 mL, 2 : 1 v/v) was refluxed for 24 h. After cooling to room temperature, the mixture was filtered, and the precipitate was washed with  $\text{H}_2\text{O}$  and petroleum ether to give the crude cyclometalated  $\text{Ir}(\text{III})$  chloro-bridged dimer. The slurry of crude chloro-bridged dimer (0.50 mmol) and KPOP (1.10 mmol) in 2-ethoxyethanol (40 mL) was refluxed for 24 h. The crude product was purified by silica column chromatography (petroleum ether : ethyl acetate = 5 : 1), which were further purified by sublimation in vacuum.

**Ir1.** 47% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  9.04 (d,  $J$  = 9.7 Hz, 1H), 8.18 (d,  $J$  = 9.5 Hz, 2H), 8.11 (dd,  $J$  = 8.0, 1.4 Hz, 2H), 8.03–7.95 (m, 4H), 7.74–7.70 (m, 1H), 7.65 (t,  $J$  = 7.1 Hz, 2H), 7.59–7.54 (m, 4H), 7.54–7.50 (m, 3H), 7.50–7.44 (m, 3H), 7.23–7.19 (m, 1H), 7.17–7.09 (m, 3H), 6.98 (ddd,  $J$  = 8.7, 6.8, 1.9 Hz, 1H), 6.75–6.69 (m, 1H), 6.66 (t,  $J$  = 7.4 Hz, 2H), 6.63–6.60 (m, 1H), 6.59–6.54 (m, 2H), 6.37 (dd,  $J$  = 7.6, 0.9 Hz, 1H), 6.12 (ddd,  $J$  = 7.9, 6.9, 1.0 Hz, 1H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  168.68, 164.84, 161.21, 157.66, 153.82, 153.04, 146.57, 137.01, 135.42, 134.04, 132.18, 131.21, 130.41, 130.10, 129.77, 129.33, 129.14, 129.06, 128.75, 128.56, 127.63, 127.14, 126.92, 125.29, 124.01, 123.03, 121.32, 120.28, 113.30, 106.94. HR EI-MS  $m/z$  calcd for  $\text{C}_{54}\text{H}_{35}\text{IrN}_6\text{O}_2$ : 992.2451  $[\text{M}]^+$ , found: 993.2560  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{54}\text{H}_{35}\text{IrN}_6\text{O}_2$ : C, 65.37; H, 3.56; N, 8.47. Found: C, 65.40; H, 3.59; N, 8.45.

**Ir2.** 40% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  9.08 (dd,  $J$  = 13.1, 8.4 Hz, 1H), 8.10–8.06 (m, 4H), 8.00 (dd,  $J$  = 8.1, 1.5 Hz, 2H), 7.76 (ddd,  $J$  = 10.6, 8.3, 2.9 Hz, 2H), 7.68–7.62 (m, 4H), 7.57–7.53 (m, 4H), 7.53–7.46 (m, 4H), 7.30 (dd,  $J$  = 8.1, 1.8 Hz, 1H), 7.22–7.19 (m, 1H), 7.14–7.10 (m, 1H), 7.07 (ddd,  $J$  = 8.7, 6.9, 1.8 Hz, 1H), 6.71–6.66 (m, 2H), 6.61 (ddd,  $J$  = 7.4, 2.8, 1.3 Hz, 2H), 6.33–6.29 (m, 1H), 6.25 (ddd,  $J$  = 8.0, 6.9, 1.0 Hz, 1H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  168.18, 165.07, 163.55, 161.30, 157.21, 154.27, 153.35, 152.89, 146.08, 144.85, 139.50, 139.33, 136.66, 135.14, 134.50, 132.47, 130.65, 130.36, 130.17, 129.71, 129.23, 127.23, 126.96,

124.22, 122.67, 121.77, 120.76, 114.09, 106.65.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -127.43 (1F), -127.49 (1F), -132.16 (1F), -132.22 (1F). HR EI-MS  $m/z$  calcd for  $\text{C}_{54}\text{H}_{31}\text{F}_4\text{IrN}_6\text{O}_2$ : 1064.2074  $[\text{M}]^+$ , found: 1065.2483  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{54}\text{H}_{31}\text{F}_4\text{IrN}_6\text{O}_2$ : C, 60.95; H, 2.94; N, 7.90. Found: C, 60.91; H, 2.89; N, 7.92.

**Ir3.** 55% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  8.98 (dd,  $J$  = 8.7 Hz, 1H), 8.19–8.14 (m, 2H), 8.10 (dd,  $J$  = 8.8, 5.3 Hz, 2H), 8.02–7.93 (m, 4H), 7.65 (d,  $J$  = 8.8 Hz, 1H), 7.60–7.45 (m, 6H), 7.35 (t,  $J$  = 8.6 Hz, 2H), 7.24–7.08 (m, 6H), 7.00 (ddd,  $J$  = 8.7, 6.9, 1.9 Hz, 1H), 6.69 (d,  $J$  = 8.7 Hz, 1H), 6.44 (tdd,  $J$  = 9.1, 6.7, 2.6 Hz, 2H), 6.25 (dd,  $J$  = 9.5, 2.6 Hz, 1H), 6.15 (ddd,  $J$  = 8.0, 6.9, 1.0 Hz, 1H), 6.00 (dd,  $J$  = 9.1, 2.6 Hz, 1H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  168.31, 163.18, 162.71, 161.07, 152.46, 151.66, 142.72, 142.43, 141.94, 140.90, 140.55, 139.72, 136.17, 135.81, 134.29, 132.52, 131.55, 130.32, 129.83, 129.57, 129.30, 129.01, 127.21, 126.84, 124.77, 123.82, 122.79, 121.30, 113.73, 106.72.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -109.37 (1F), -109.73 (1F), -110.55 (1F), -110.56 (1F). HR EI-MS  $m/z$  calcd for  $\text{C}_{54}\text{H}_{31}\text{F}_4\text{IrN}_6\text{O}_2$ : 1064.2074  $[\text{M}]^+$ , found: 1065.2366  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{54}\text{H}_{31}\text{F}_4\text{IrN}_6\text{O}_2$ : C, 60.95; H, 2.94; N, 7.90. Found: C, 60.96; H, 2.90; N, 7.88.

**Ir4.** 60% yield.  $^1\text{H}$  NMR (400 MHz,  $\text{CDCl}_3$ )  $\delta$  9.02 (dd,  $J$  = 13.0, 8.3 Hz, 1H), 8.07 (dd,  $J$  = 8.2, 4.9 Hz, 4H), 7.97 (dt,  $J$  = 6.9, 1.4 Hz, 1H), 7.79–7.72 (m, 2H), 7.61–7.52 (m, 4H), 7.36 (t,  $J$  = 8.5 Hz, 1H), 7.32 (d,  $J$  = 1.9 Hz, 1H), 7.22 (dd,  $J$  = 9.0, 5.7 Hz, 2H), 7.16–7.06 (m, 4H), 6.75 (d,  $J$  = 8.7 Hz, 1H), 6.48 (qd,  $J$  = 8.8, 2.7 Hz, 3H), 6.31–6.26 (m, 1H), 6.22–6.18 (m, 1H), 5.94 (dd,  $J$  = 8.9, 2.6 Hz, 1H).  $^{13}\text{C}$  NMR (101 MHz,  $\text{CDCl}_3$ )  $\delta$  167.53, 163.96, 162.56, 160.83, 152.80, 152.33, 151.54, 150.10, 149.72, 146.02, 143.11, 135.49, 135.22, 134.85, 132.16, 131.85, 131.15, 130.05, 128.64, 127.15, 126.86, 125.77, 124.99, 124.60, 123.53, 122.35, 121.28, 120.77, 112.45, 107.10.  $^{19}\text{F}$  NMR (376 MHz,  $\text{CDCl}_3$ )  $\delta$  -108.04 (2F), -108.53 (2F), -109.66 (2F), -109.72 (2F). HR EI-MS  $m/z$  calcd for  $\text{C}_{54}\text{H}_{27}\text{F}_8\text{IrN}_6\text{O}_2$ : 1136.1697  $[\text{M}]^+$ , found: 1137.2035  $[\text{M} + \text{H}]^+$ . Anal. calcd for  $\text{C}_{54}\text{H}_{27}\text{F}_8\text{IrN}_6\text{O}_2$ : C, 57.09; H, 2.40; N, 7.40. Found: C, 57.11; H, 2.45; N, 7.38.

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## Notes and references

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